GLF1131HT, GLF1133HT

Nano-Current Consumed, I_QSmart[™] Power Load Switch with Slew Rate Control Preliminary Specification

DESCRIPTION

The GLF1131HT and GLF1133HT are a highly efficient load switch, specifically designed for applications where low power consumption and high performance are crucial, such as in IoT (Internet of Things) devices, mobile electronics, and wearables.

The GLF1131HT and GLF1133HT are highly efficient components, leveraging I_QSmart^{TM} technology to keep the quiescent current (I_Q) and shutdown current (I_{SD}) as low as possible. With low I_Q and I_{SD} , the device consumes less power in idle or shutdown states, meaning the system can operate for longer periods without draining the battery.

The GLF1131HT and GLF1133HT integrated slew rate control offers a significant advantage in improving system reliability by managing the voltage transitions more smoothly during switching events. By controlling the rate of voltage change during turn-on, the GLF1131HT and GLF1133HT effectively limit the inrush current, ensuring that the system remains stable and minimizing the risk of voltage dips. This protection mechanism helps maintain consistent performance and reduces the likelihood of unwanted resets or disruptions in the power supply.

The GLF1131HT and GLF1133HT are designed to offer a wide input voltage range, which is a significant advantage in terms of system flexibility and performance. It makes the device versatile enough to be used in multiple voltage rail applications. As a result, it can simplify inventory management and help reduce operating costs, as fewer devices are needed for various applications.

FEATURES

Wide Input Range: 1.1 V to 5.5 V

6 Vabs max

Ultra-Low IQ: 2 nA Typ at 5.5 VIN

Ultra-Low I_{SD}: 19 nA Typ at 5.5 V_{IN}

• Low R_{ON} = 34 m Ω Typ. at 5.5 V_{IN}

• Iouт Max = 2.0 A

• Controlled Rise Time:

450 μs at 3.3V_{IN}: GLF1131HT

2450 μs at 3.3V_{IN}: GLF1133HT

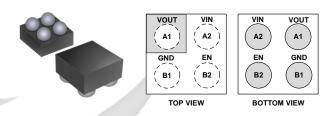
Integrated Output Discharge Switch

· Compatible with lower enable voltage systems

APPLICATIONS

- Wearables
- Data Storage, SSD
- Mobile Devices
- Low Power Subsystems
- IoT Devices

PACKAGE



0.77 mm x 0.77 mm x 0.35 mm Thin WLCSP

APPLICATION DIAGRAM

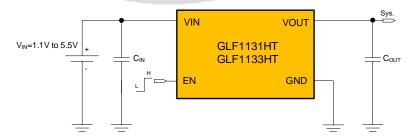
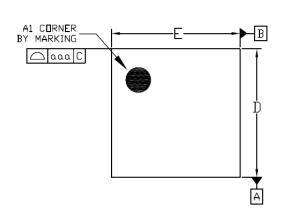
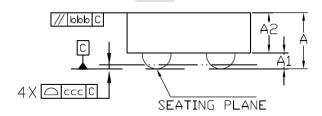


Figure 1. Application Diagram

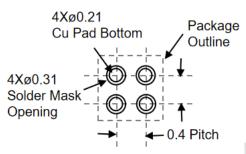
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Nano-Current Consumed, I₀Smart™ Power Load Switch with Slew Rate Control

PACKAGE OUTLINE





Recommended Footprint



Notes

- 1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGRESS)
- 2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.

	SE 2	1 1	
D1			T A
D1 T			B B
	4	Øb Øddd()() [C	ВА

D: : 1 D (
Dimensional Ref.							
REF.	Min.	Nom.	Max.				
Α	0.300	0.350	0.400				
Α1	0.075	0.100	0.125				
Α2	0.225	0.250	0.275				
D	0.755	0.770	0.785				
E	0.755	0.770	0.785				
D1	0.350	0.400	0.450				
E1	0.350	0.400	0.450				
Ь	0.145	0.180	0.215				
е	0.400 BSC						
SD	0.200 BSC						
SE	0.200 BSC						
Tol. of Form&Position							
ааа	0.10						
ЬЬЬ	0.10						
CCC	0.05						
ddd	0.05						

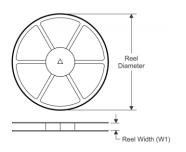
PACKAGING INFORMATION

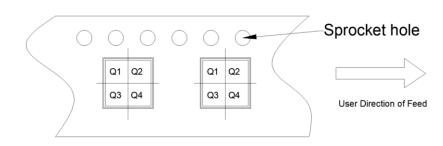
Part Number	Package	Pins	Pitch	Top Mark Moisture Sensitivity Level		Environmental Information	
GLF1131HT-S17	WLCSP	4	0.40mm	5	MSL1	ROHS+HF	
GLF1133HT-S17	WLCSP	4	0.40mm	7	MSL1	ROHS+HF	

TAPE AND REEL INFORMATION

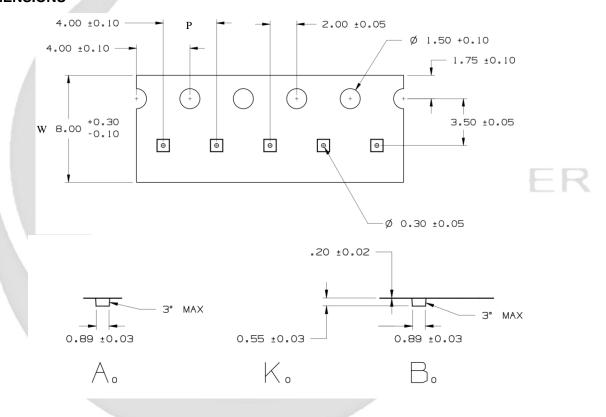
REEL DIMENSIONS

QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE





TAPE DIMENSIONS



Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	Α0	В0	K0	Р	w	Pin1
GLF1311HT-S17	WLCSP	4	4000	180	9	0.89	0.89	0.55	4	8	Q1
GLF1133HT-S17	WLCSP	4	4000	180	9	0.89	0.89	0.55	4	8	Q1

Remark:

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P: Pitch between successive cavity centers